# **74AUP1G32**

# Low-power 2-input OR-gate

Rev. 8 — 28 January 2019

**Product data sheet** 

## 1. General description

The 74AUP1G32 provides the single 2-input OR function.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package	Package						
	Temperature range	Name	Description	Version				
74AUP1G32GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G32GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1G32GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891				
74AUP1G32GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP1G32GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1G32GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226				

## 4. Marking

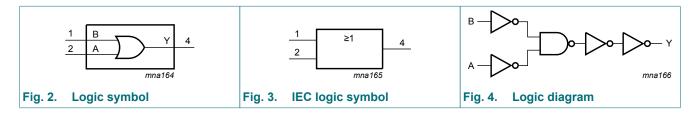
Table 2. Marking

Type number	Marking code [1]
74AUP1G32GW	pG
74AUP1G32GM	pG
74AUP1G32GF	pG
74AUP1G32GN	pG
74AUP1G32GS	pG
74AUP1G32GX	pG

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram

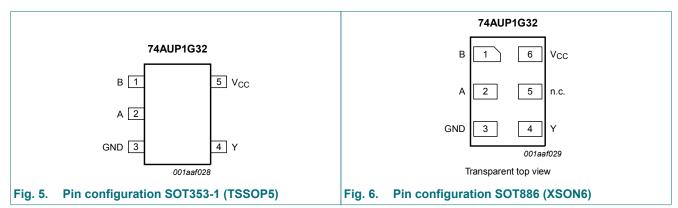
Fig. 1.

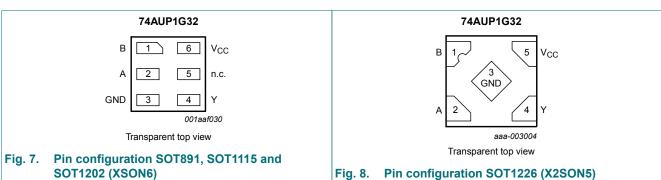


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# 6. Pinning information

### 6.1. Pinning





## 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	TSSOP5 and X2SON5	XSON6		
В	1	1	data input	
A	2	2	data input	
GND	3	3	ground (0 V)	
Υ	4	4	data output	
n.c.	-	5	not connected	
V <sub>CC</sub>	5	6	supply voltage	

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# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input		Output
A	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
V <sub>O</sub>	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	V <sub>O</sub> = 0 V to V <sub>CC</sub>	-	±20	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
V <sub>O</sub>	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

<sup>[2]</sup> For TSSOP5 packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

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## 10. Static characteristics

**Table 7. Static characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH}$ or $V_{IL}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_{I} = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.1	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>1</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
Δl <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_0 = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.8	-	pF
Co	output capacitance	$V_O = GND$ ; $V_{CC} = 0 V$	-	1.7	-	pF

Symbo	I Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> =	-40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	_	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ
T <sub>amb</sub> =	-40 °C to +125 °C					'
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.75 × V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.25 × V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
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### Low-power 2-input OR-gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.75	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

# 11. Dynamic characteristics

## **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 5 pF					
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [2]				
		V <sub>CC</sub> = 0.8 V	-	16.8	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.4	5.1	10.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.6	3.6	6.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.4	3.0	5.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	2.4	3.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.1	3.5	ns

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Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 10 pF					
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [2	]			
		V <sub>CC</sub> = 0.8 V	-	20.3	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.3	5.9	12.7	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.9	4.2	7.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.7	3.5	6.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.9	4.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.7	4.3	ns
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 15 pF		-			
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [2	]			
		V <sub>CC</sub> = 0.8 V	-	23.8	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.3	6.7	14.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.8	8.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	4.0	6.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.3	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	3.1	4.9	ns
T <sub>amb</sub> = 2	5 °C; C <sub>L</sub> = 30 pF		-1			
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [2	]			
		V <sub>CC</sub> = 0.8 V	-	34.1	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.5	9.0	19.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.4	6.3	11.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	5.3	8.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.3	4.4	7.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.2	4.2	6.4	ns
T <sub>amb</sub> = 2	5 °C	,				
C <sub>PD</sub>	power dissipation	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3	]			
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.5	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.6	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.8	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	2.9	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.4	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	3.9	-	pF
			1			

<sup>[1]</sup> All typical values are measured at nominal  $V_{CC}$ .

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

 $f_o$  = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

 <sup>[2]</sup> t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
 [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

Low-power 2-input OR-gate

**Table 9. Dynamic characteristics** 

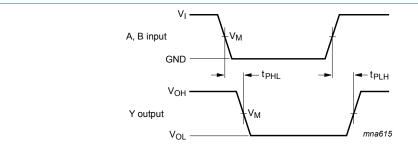
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10

Symbol	Parameter	Conditions	-40 °C 1	to +85 °C	-40 °C to	+125 °C	Unit
			Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.1	11.9	2.1	13.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.4	7.5	1.4	8.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.2	6.0	1.2	6.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	4.6	1.0	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.9	4.1	0.9	4.6	ns
C <sub>L</sub> = 10	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [1					
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.1	13.8	2.1	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.7	8.7	1.7	9.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.5	6.9	1.5	7.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.3	5.5	1.3	6.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.2	5.0	1.2	5.5	ns
C <sub>L</sub> = 15	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [1]					
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.0	15.6	3.0	17.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.0	9.8	2.0	10.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.8	7.9	1.8	8.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	6.3	1.6	6.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	5.8	1.5	6.4	ns
C <sub>L</sub> = 30	pF						
t <sub>pd</sub>	propagation delay	A, B to Y; see <u>Fig. 9</u> [1					
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.0	21.5	4.0	23.7	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.9	13.3	2.9	14.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.4	10.7	2.4	11.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.2	8.4	2.2	9.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	7.7	2.1	8.5	ns

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

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### 11.1. Waveforms and test circuit



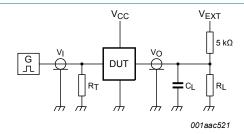
Measurement points are given in Table 10.

Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drop that occur with the output load.

Fig. 9. The data input (A or B) to output (Y) propagation delays

**Table 10. Measurement points** 

Supply voltage	Output	Input			
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$	
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 10. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k $\Omega$ or 1 M $\Omega$	open	GND	2 × V <sub>CC</sub>

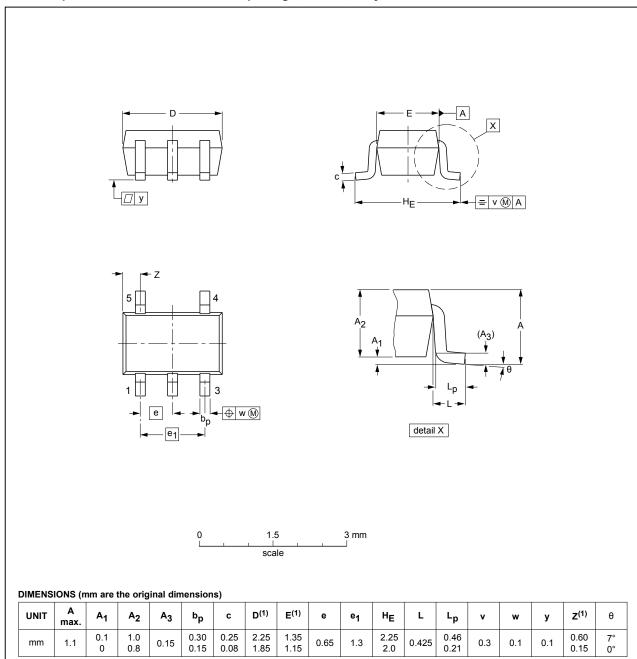
[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

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# 12. Package outline

### TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	NE REFERENCES		ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A		<del>-00-09-01</del> 03-02-19

Fig. 11. Package outline SOT353-1 (TSSOP5)

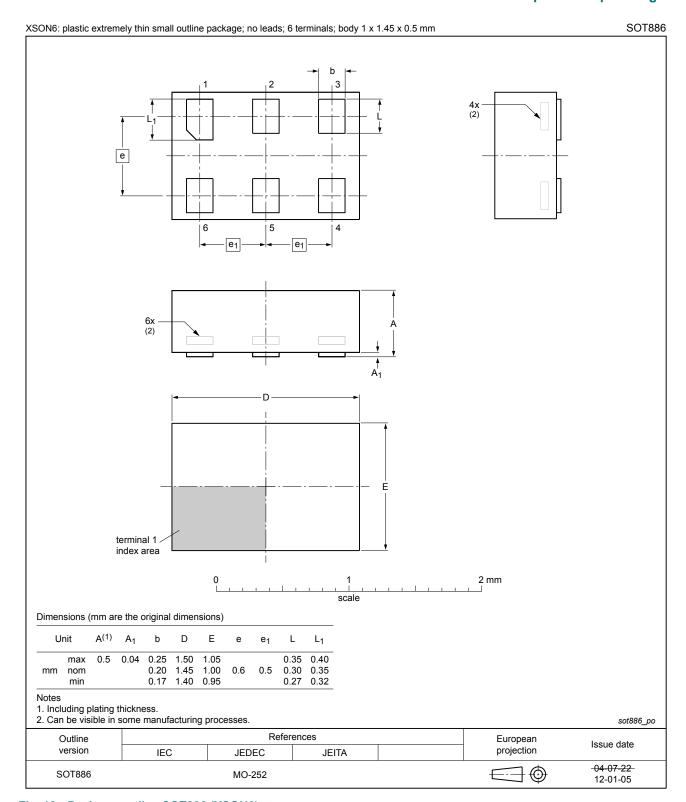


Fig. 12. Package outline SOT886 (XSON6)

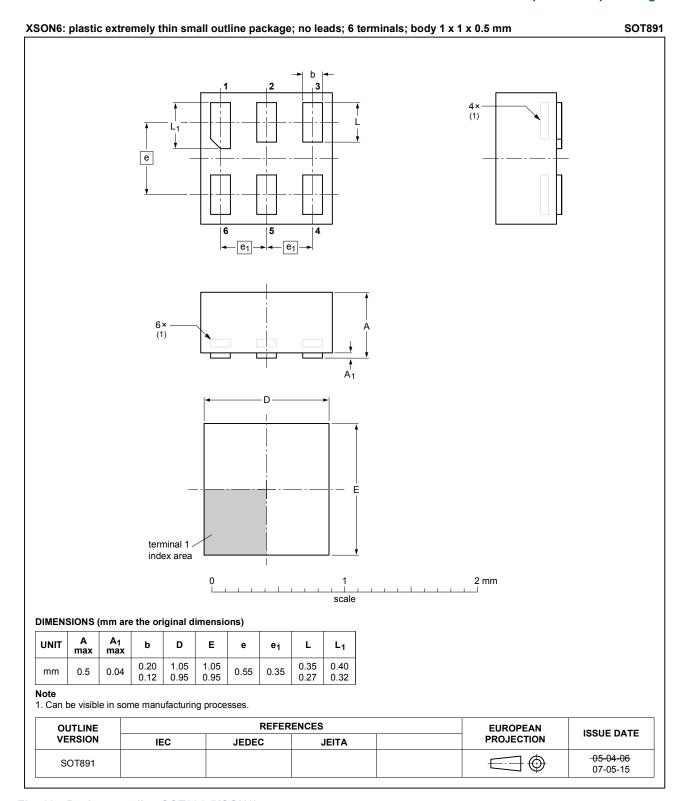


Fig. 13. Package outline SOT891 (XSON6)

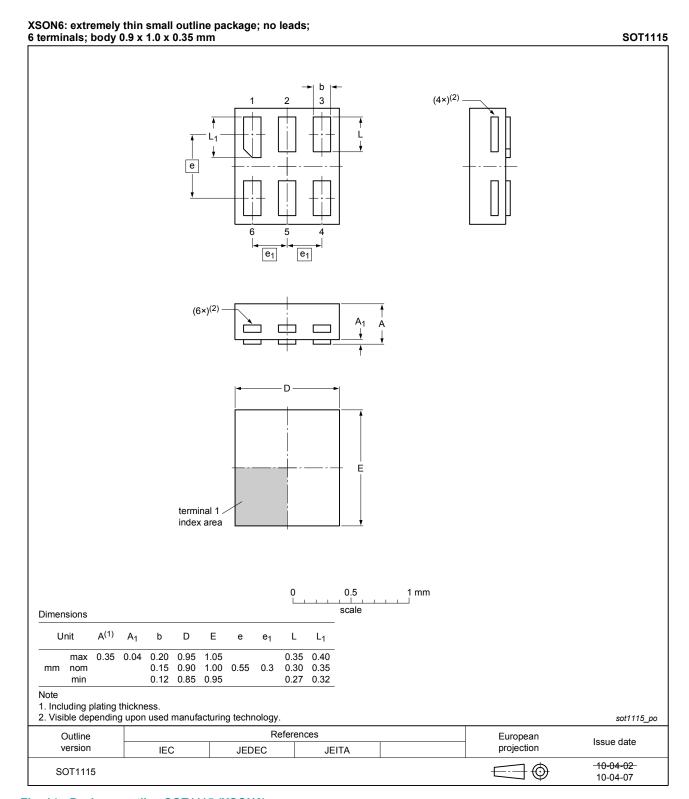


Fig. 14. Package outline SOT1115 (XSON6)

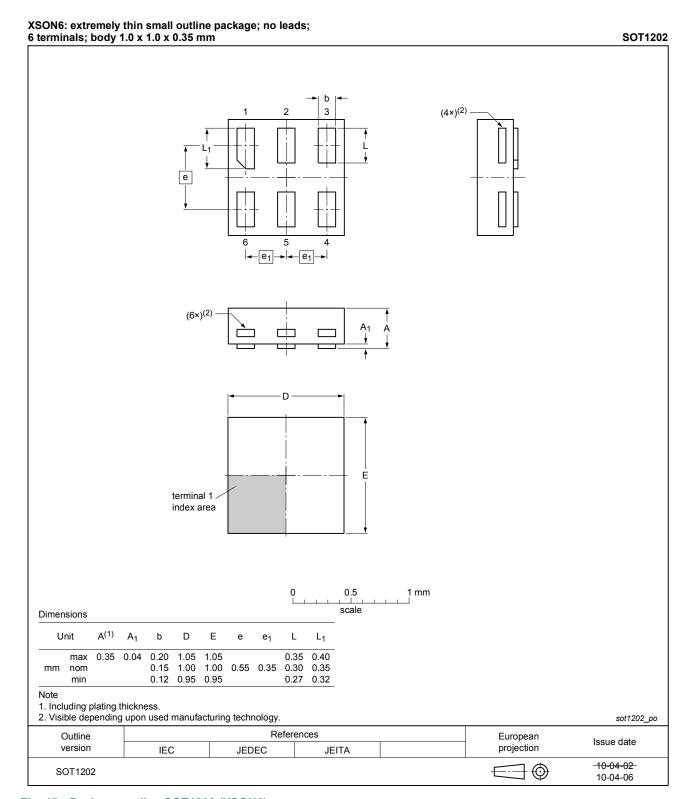


Fig. 15. Package outline SOT1202 (XSON6)

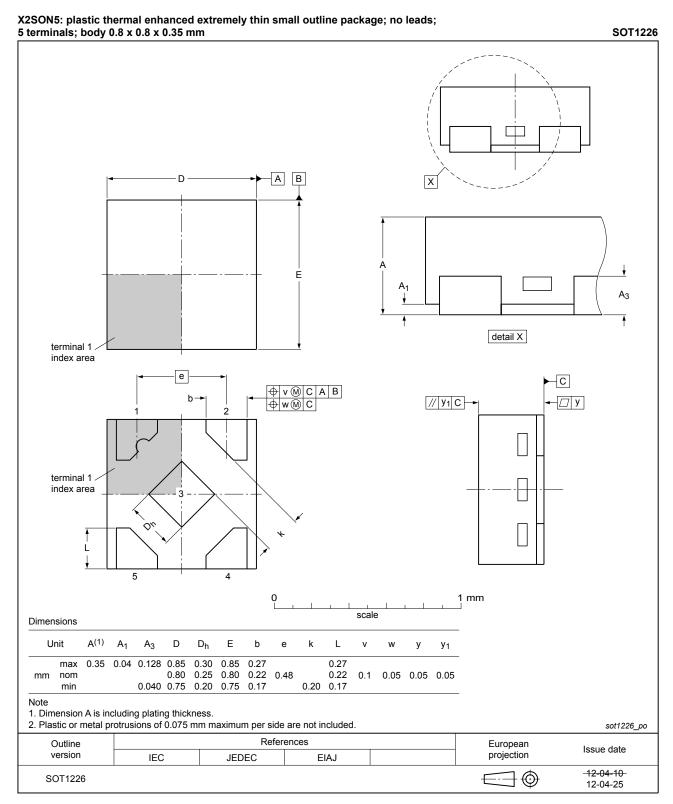


Fig. 16. Package outline SOT1226 (X2SON5)

**Low-power 2-input OR-gate** 

## 13. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

#### **Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1G32 v.8	20190128	Product data sheet	-	74AUP1G32 v.7		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Typical values C<sub>I</sub> and C<sub>O</sub> corrected (errata).</li> </ul>					
74AUP1G32 v.7	20130708	Product data sheet	-	74AUP1G32 v.6		
Modifications:	Descriptive p	Descriptive product title on page 1 change to Low-power 2-input OR-gate				
74AUP1G32 v.6	20130705	Product data sheet	-	74AUP1G32 v.5		
74AUP1G32 v.5	20120628	Product data sheet	-	74AUP1G32 v.4		
Modifications:	<ul> <li>Added type number 74AUP1G32GX (SOT1226)</li> <li>Package outline drawing of SOT886 (Figure 11) modified.</li> </ul>					
74AUP1G32 v.4	20111123	Product data sheet	-	74AUP1G32 v.3		
Modifications:	Legal pages updated.					
74AUP1G32 v.3	20101012	Product data sheet	-	74AUP1G32 v.2		
74AUP1G32 v.2	20060721	Product data sheet	-	74AUP1G32 v.1		
74AUP1G32 v.1	20050802	Product data sheet	-	-		

#### Low-power 2-input OR-gate

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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